

Surface Mounted Schottky Barrier Rectifier SMAFAB54J

SMAFAB54J is designed as a metal-silicon junction to achiece low forward voltage. It enables low power loss and high efficiency.

FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- · Low power loss, high efficiency
- · Low leakage current
- Package size: 3.5X2.55X1.05mm³
- Pb-Free, Halogen-Free, Rohs compliant

MECHANICAL DATA

· Package: SMAFA

• Terminal: Solderable per MIL-STD-750, Method 2026

• Polarity indicator: Cathode band

• Weight: ≒0.027grams

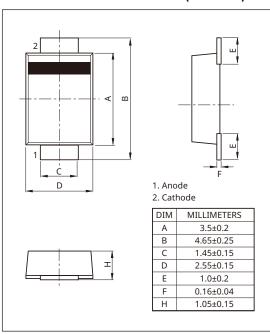
APPLICATION

- DC/DC
- SMPS
- AC-DC
- Reverse polarity protection
- Freewheeling
- Blocking

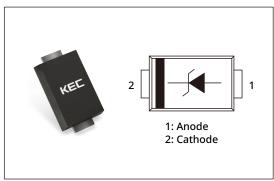
ORDERING INFORMATION

PART NUMBER	QTY PER BOX	BOX SIZE
SMAFAB54J	3,000	7inch

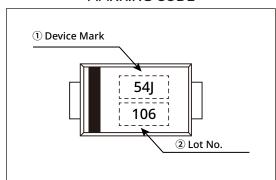
PACKAGE DIMENSION(SMAFA)



PIN CONFIGURATION



MARKING CODE



MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	40	V
Maximum RMS Voltage	V _{RMS}	28	V
Maximum DC Blocking Voltage	V _{DC}	40	V
Average Output Rectified Current	I _o	5	Α
Peak forward surge current with 8.3ms single half sine wave (Note 1, Note 2)	I _{FSM}	150	А
Junction Temperature	T _j	150	°C
Operating Junction Temperature	T _{opr}	-55~150	°C
Storage Temperature	T _{STG}	-55~150	°C

Note 1) Non-repetitive pulse

Note 2) Mounted on a pad dimension 5X5cm to each terminals

THERMAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	VALUE	UNIT
Thermal Resistance (Note 2)	Rth(j-a)	Junction to Ambient	45	°C/W

Note 2) Mounted on a pad dimension 5X5cm to each terminals

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	MIN.	TYP.	MAX.	UNIT
Forward Voltage	V_{F}	I _F =5A	-	-	0.52	٧
Reverse Leakage Current	I_R	V _R =40V	-	-	150	μΑ
Total Capacitance	C _T	V _R =4V, f=1MHz	-	500	-	pF

Fig.1 Forward Current Derating Curve

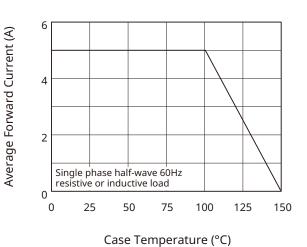


Fig.3 Typical Forward Characteristic

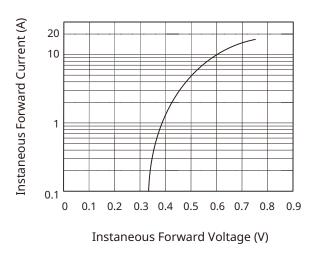


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current

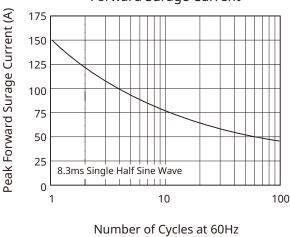
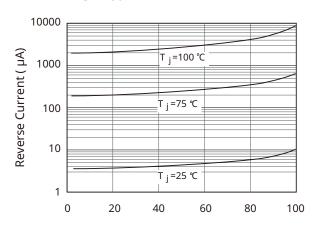


Fig.2 Typical Reverse Characteristics



Percent of Rated Peak Reverse Voltage $\ (\%)$

Fig.4 Total Capacitance

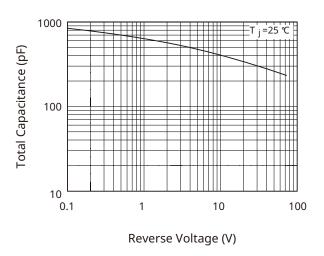
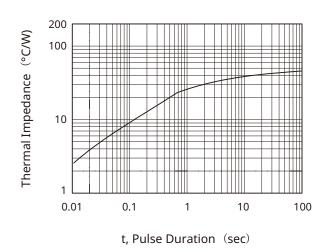
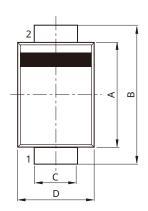


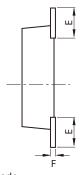
Fig.6 Thermal Impedance



Surface Mounted Schottky Barrier Rectifier - SMAFAB54J

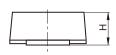
PACKAGE INFORMATION(SMAFA)





1. Anode

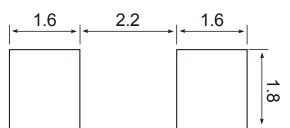
2. Cathode



DIM	MILLIMETERS
Α	3.5±0.2
В	4.65±0.25
С	1.45±0.15
D	2.55±0.15
Е	1.0±0.2
F	0.16±0.04
Н	1.05±0.15

RECOMMENDED PAD DIMENSION

Unit:mm



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